

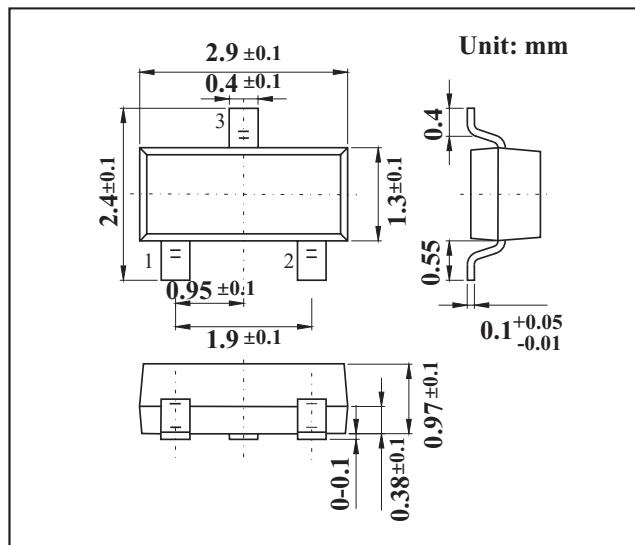
SOT-23 Plastic-Encapsulate MOSFETS

FEATURE

- TrenchFET Power MOSFET
- N-Channel Enhancement Mode Field Effect Transistor

MECHANICAL DATA

- Case style:SOT-23molded plastic
- Mounting position:any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	30	V
Gate-source voltage	V_{GS}	±20	V
Continuous drain current (t ≤ 10s)	I_D	5.8	A
Pulsed drain current *	I_{DM}	30	A
Thermal resistance from junction to ambient	$R_{\theta JA}$	357	°C/W
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~ 150	°C

* Repetitive rating : Pulse width limited by maximum junction temperature.

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
30V	30mΩ@ 10V	5.8A
	42mΩ@4.5V	

MOSFET ELECTRICAL CHARACTERISTICS Ta=25 °C unless otherwise specified

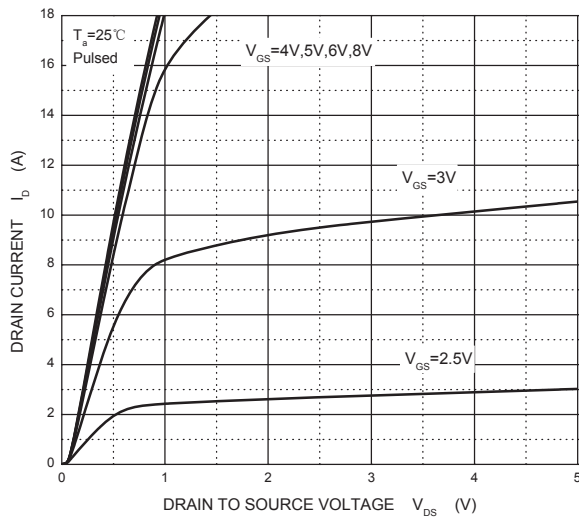
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 30V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1	1.4	3	V
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 5.8A$		23	30	m Ω
		$V_{GS} = 4.5V, I_D = 4.8A$		31	42	Ω
Forward tranconductance (note 1)	g_{FS}	$V_{DS} = 5V, I_D = 5.8A$	5			S
Diode forward voltage	V_{SD}	$I_S = 1A$			1	V
DYNAMIC PARAMETERS (note 2)						
Input capacitance	C_{iss}	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$			820	pF
Output capacitance	C_{oss}			118		pF
Reverse transfer capacitance	C_{rss}			85		pF
Gate resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$			1.5	Ω
SWITCHING PARAMETERS (note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 15V, R_L = 2.6\Omega, R_{GEN} = 3\Omega$			6.5	ns
Turn-on rise time	t_r			3.1		ns
Turn-off delay time	$t_{d(off)}$			15.1		ns
Turn-off fall time	t_f			2.7		ns

Note :

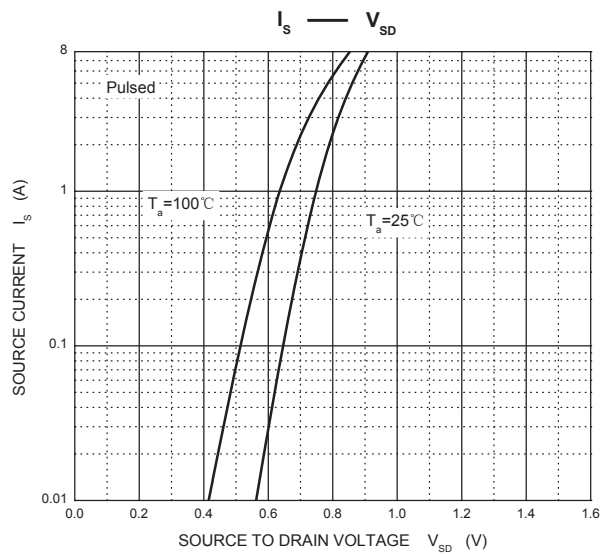
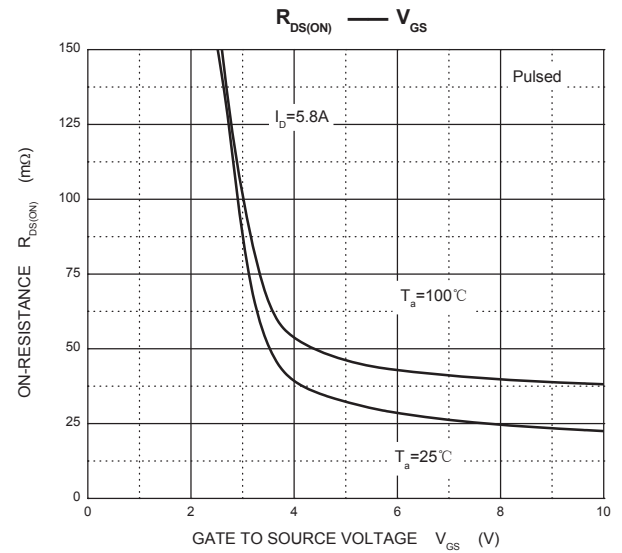
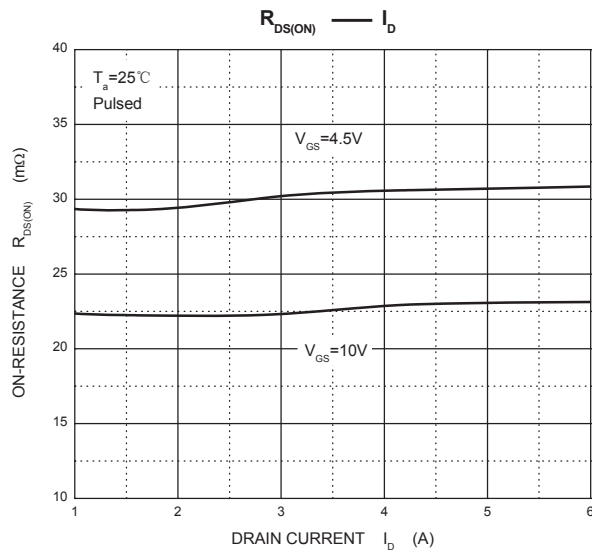
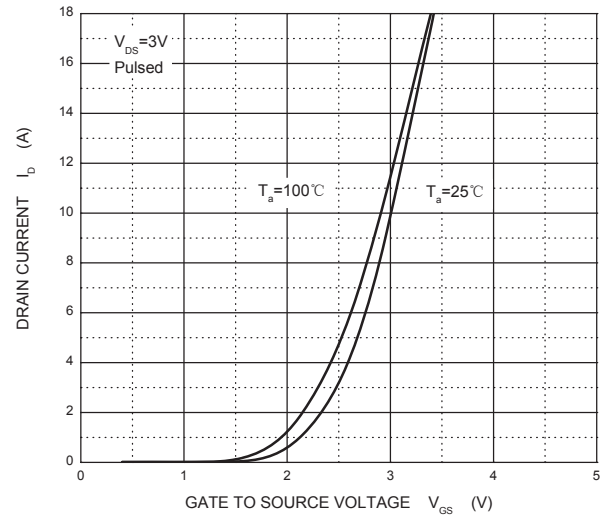
1. Pulse Test : Pulse width $\leq 300\mu s$, duty cycle $\leq 0.5\%$.
2. These parameters have no way to verify.

RATINGS AND CHARACTERISTIC CURVES

Output Characteristics



Transfer Characteristics



Threshold Voltage

